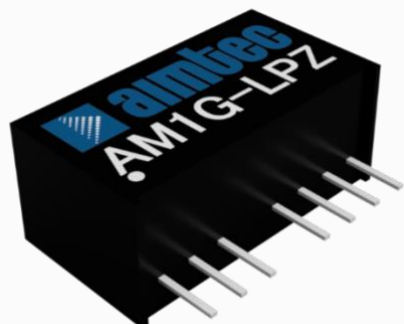


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AM1G-LPZ



SIP8 Package

The AM1G-LPZ is a 1W SIP8 DC/DC converter that offers great cost savings thanks to an improved manufacturing process. It also features excellent reliability and performance while offering a wide input voltage range of 4.5-75VDC as well as an output voltage of -15 to 24V. This compact SIP8 design will surely benefit your new system design.

This new series offers a great operating temperature range from -40 to 85°C. Also, an isolation of 1500VDC for improved reliability and system safety as well as a great 1,000,000h MTBF come standard.

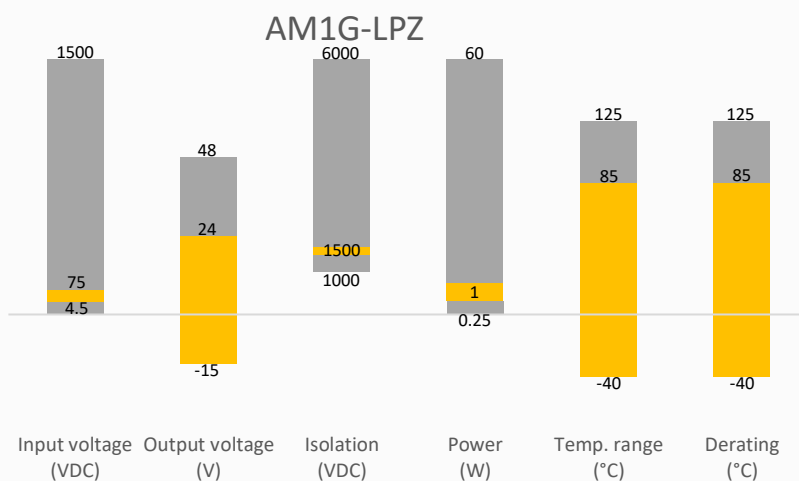
The AM1G-LPZ is suitable for many applications such as industrial systems, portable equipment, and internet of things.

Features

- High I/O Isolation of 1500VDC
- Continuous Short circuit protection
- Operating Temp: -40 °C to +85 °C
- Industry standard SIP8 pin-out
- Regulated output



Summary



Training



Product Training Video
(click to open)



Press Release

Coming Soon!

Application Notes

Applications



Industrial



Portable Equipment



IoT

Models & Specifications



Single Output

Model	Input Voltage (VDC)	Output Voltage (VDC)	Output Current Max/Min (mA)	Isolation (VDC)	Maximum Capacitive Load (μF)	Efficiency Typ. (%)
AM1G-0503SLPZ	5 (4.5-9)	3.3	303/15	1500	1800	71
AM1G-0505SLPZ	5 (4.5-9)	5	200/15	1500	2200	72
AM1G-0512SLPZ	5 (4.5-9)	12	83/4	1500	680	76
AM1G-0515SLPZ	5 (4.5-9)	15	67/3	1500	470	75
AM1G-0524SLPZ	5 (4.5-9)	24	42/2	1500	330	73
AM1G-1203SLPZ	12 (9-18)	3.3	303/15	1500	2700	75
AM1G-1205SLPZ	12 (9-18)	5	200/10	1500	2200	77
AM1G-1209SLPZ	12 (9-18)	9	111/6	1500	1000	79
AM1G-1212SLPZ	12 (9-18)	12	83/4	1500	680	78
AM1G-1215SLPZ	12 (9-18)	15	67/3	1500	470	80
AM1G-1224SLPZ	12 (9-18)	24	42/2	1500	330	76
AM1G-2403SLPZ	24 (18-36)	3.3	303/15	1500	2700	75
AM1G-2405SLPZ	24 (18-36)	5	200/10	1500	2200	77
AM1G-2412SLPZ	24 (18-36)	12	83/4	1500	680	78
AM1G-2415SLPZ	24 (18-36)	15	67/3	1500	470	78
AM1G-2424SLPZ	24 (18-36)	24	42/2	1500	330	77
AM1G-4803SLPZ	48 (36-75)	3.3	303/15	1500	2700	75
AM1G-4805SLPZ	48 (36-75)	5	200/10	1500	2200	76
AM1G-4812SLPZ	48 (36-75)	12	83/4	1500	680	80
AM1G-4815SLPZ	48 (36-75)	15	67/3	1500	470	79

Dual Output

Model	Input Voltage (VDC)	Output Voltage (VDC)	Output Current Max/Min (mA)	Isolation (VDC)	Maximum Capacitive Load (μF)	Efficiency Typ. (%)
AM1G-0505DLPZ	5 (4.5-9)	±5	±100/±5	1500	±1000	73
AM1G-0512DLPZ	5 (4.5-9)	±12	±42/±2	1500	±470	76
AM1G-0515DLPZ	5 (4.5-9)	±15	±33/±2	1500	±330	75
AM1G-1205DLPZ	12 (9-18)	±5	±100/±5	1500	±1000	77
AM1G-1212DLPZ	12 (9-18)	±12	±42/±2	1500	±470	81
AM1G-1215DLPZ	12 (9-18)	±15	±33/±2	1500	±330	78
AM1G-2405DLPZ	24 (18-36)	±5	±100/±5	1500	±1000	79
AM1G-2412DLPZ	24 (18-36)	±12	±42/±2	1500	±470	78
AM1G-2415DLPZ	24 (18-36)	±15	±33/±2	1500	±330	78
AM1G-4805DLPZ	48 (36-75)	±5	±100/±5	1500	±1000	76
AM1G-4812DLPZ	48 (36-75)	±12	±42/±2	1500	±470	78
AM1G-4815DLPZ	48 (36-75)	±15	±33/±2	1500	±330	80

Input Specification

Parameters	Conditions	Typical	Maximum	Units
Input current	5V _{in}	281		mA
	12V _{in}	111		mA
	24V _{in}	55		mA

	48Vin	27		mA
Filter	Capacitor			
Voltage Types	Vo, Io Nom		2:1	
Maximum Rating	5Vin	> -0.7	12	VDC
	12Vin	> -0.7	25	VDC
	24Vin	> -0.7	50	VDC
	48Vin	> -0.7	100	VDC
Peak Input Voltage Time			1	Sec
No load input current	5Vin	40	60	mA
	12Vin	15	30	mA
	24Vin	6	10	mA
	48Vin	4	6	mA
Startup input voltage	5Vin		4.5	VDC
	12Vin		9	VDC
	24Vin		18	VDC
	48Vin		36	VDC
Input Reflected Ripple Current	5Vin	40		mA
	12Vin	40		mA
	24Vin	55		mA
	48Vin	55		mA
On/Off Control	ON – open or logic high, positive logic	>3.5	12	VDC
	OFF – grounded or logic low, positive logic	>0	0.7	VDC
	Control pin current, positive logic	5	10	mA

Isolation Specification

Parameters	Conditions	Typical	Maximum	Units
Tested I/O voltage	60 sec, leakage ≤ 1mA, other models	1500		VDC
Resistance	500VDC	>1000		MΩ
Capacitance	100KHz, 0.1V	120		pF

Output Specification

Parameters	Conditions	Typical	Maximum	Units
Voltage Tolerance	100% Full Load, 3.3Vout and 5Vout model	±2	±5	%
	100% Full Load, others	±1	±3	%
Line Regulation	Full load	±0.2	±0.5	%
Load regulation	25% load step	±0.5	±1	%
Temperature coefficient		±0.02	±0.03	%/°C
Transient Recovery Time	25% load step	0.5	2	mS
Transient Response Deviation	25% load step	±2.5	±5	%
Ripple & Noise*		80	150	mV p-p

* Ripple and Noise are measured at 20MHz bandwidth. Please refer to the application note for specific details.

General Specifications

Parameters	Conditions	Typical	Maximum	Units
Switching frequency	100% load	250		KHz
Short circuit protection	Continuous, auto-recovery			
Operating temperature		-40 to +85		°C
Storage temperature		-55 to +125		°C
Lead Temperature	1.5mm from case for 10 seconds		300	°C

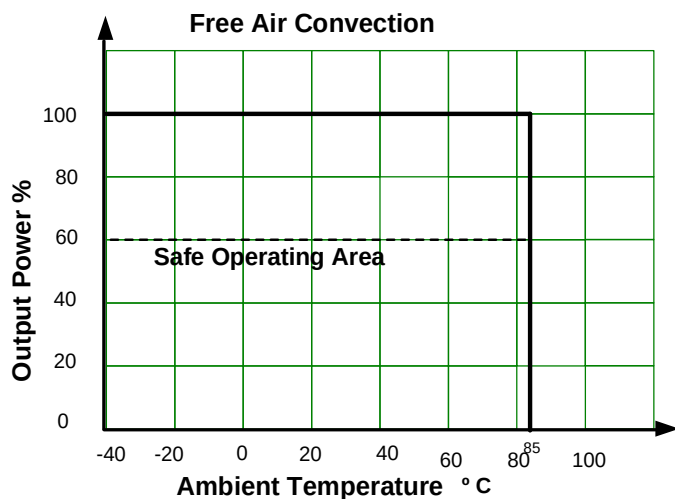
Cooling	Free air convection			
Humidity	Non-condensing	>5	95	% RH
Case material	Plastic (UL94V-0)			
Weight		4		g
Dimensions (L x W x H)	0.87 x 0.37 x 0.47 inches (22.00 x 9.50 x 12.00 mm)			
MTBF	1 000 000 hrs (MIL-HDBK -217F, t=+25°C) / Full Load			
NOTE: All specifications in this datasheet are measured at an ambient temperature of 25°C, humidity<75%, nominal input voltage and at rated output load unless otherwise specified.				

Safety Specifications

Parameters

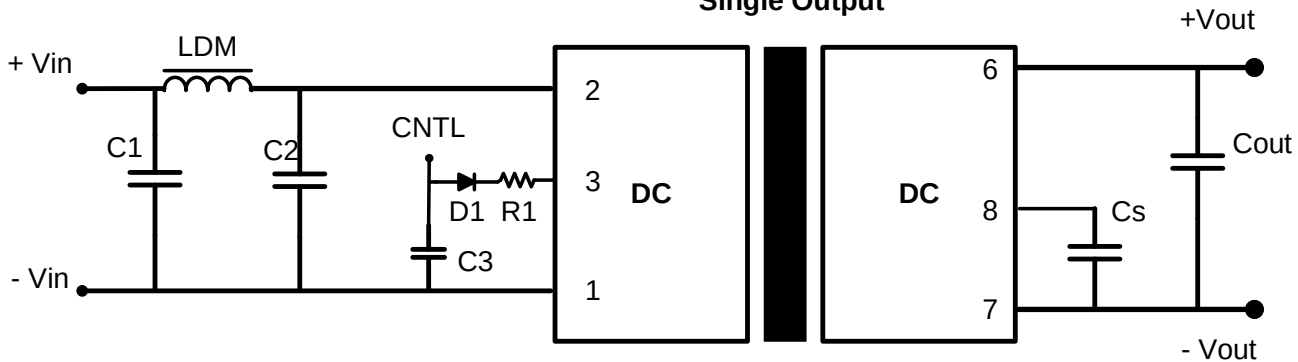
Standards	Designed to meet UL/EN/IEC 62368-1	
	EMI - Conducted and radiated emission	CISPR32/EN55032 Class B with EMI recommended circuit
	Electrostatic Discharge Immunity	IEC/EN 61000-4-2, Contact $\pm 4\text{KV}$ perf. Criteria B
	RF, Electromagnetic Field Immunity	IEC/EN 61000-4-3, 10V/m, Criteria A
	Electrical Fast Transient/Burst Immunity	IEC/EN 61000-4-4, $\pm 2\text{KV}$ with recommended EMC circuit, Criteria B
	Surge Immunity	IEC/EN 61000-4-5, L-L $\pm 2\text{KV}$, Criteria B
	RF, Conducted Disturbance Immunity	IEC/EN 61000-4-6, 3 V _{r.m.s} , Criteria A
	Voltage dips, Short Interruptions & Voltage variations Immunity	IEC/EN 61000-4-29, 0-70%, Criteria B

Derating

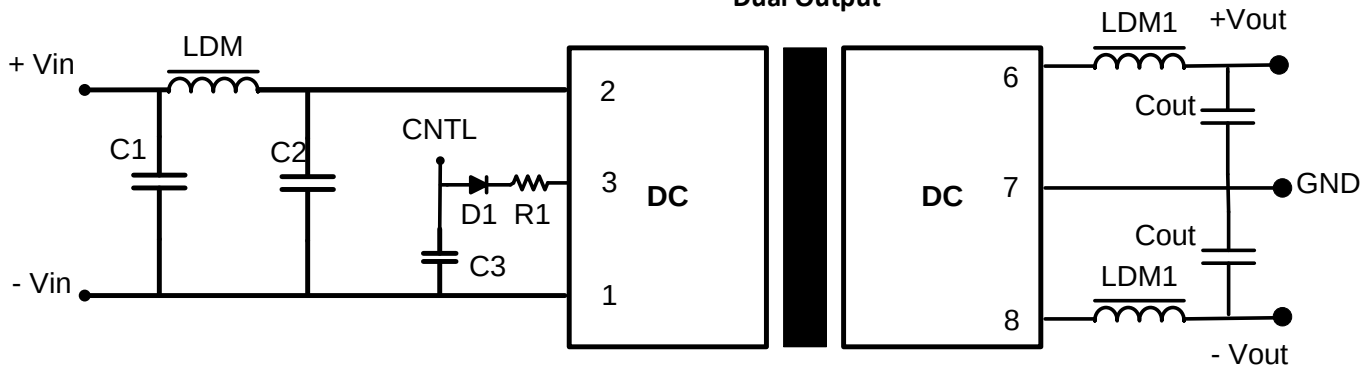


Typical application circuit

Single Output

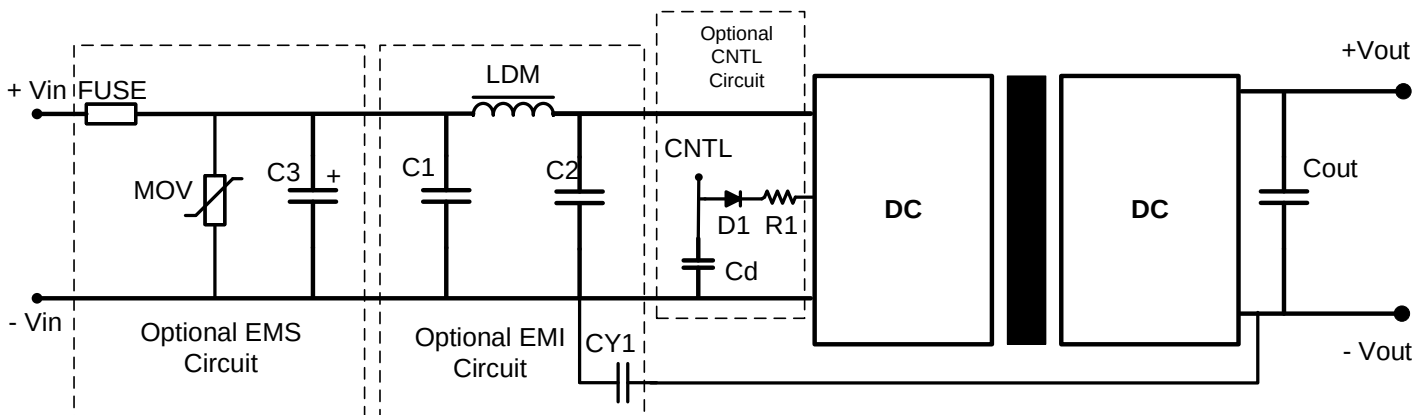


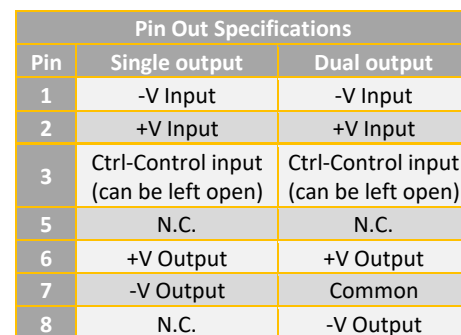
Dual Output



Model	C1	C2	Cout	C3	Cs	LDM	LDM1	D1	R1
5Vin	100 μ F	47 μ F	100 μ F	47nF/100V	10 μ F~22 μ F	47 μ H~12 μ H	2.2 μ H~10 μ H	60V, 1A	See formula
12Vin	100 μ F	47 μ F	100 μ F	47nF/100V	10 μ F~22 μ F	47 μ H~12 μ H	2.2 μ H~10 μ H	60V, 1A	See formula
24Vin	10 μ F	1 μ F	100 μ F	47nF/100V	10 μ F~22 μ F	47 μ H~12 μ H	2.2 μ H~10 μ H	60V, 1A	See formula
48Vin	10 μ F	1 μ F	100 μ F	47nF/100V	10 μ F~22 μ F	47 μ H~12 μ H	2.2 μ H~10 μ H	60V, 1A	See formula

EMI recommended circuit



$$R1 = ((V_{cd} - V_{d1} - 1.0) / I_{cnt1}) - 300$$


General tolerances: $\pm 0.25(\pm 0.01)$

6